

Model Number # AML811P5011

ITAR

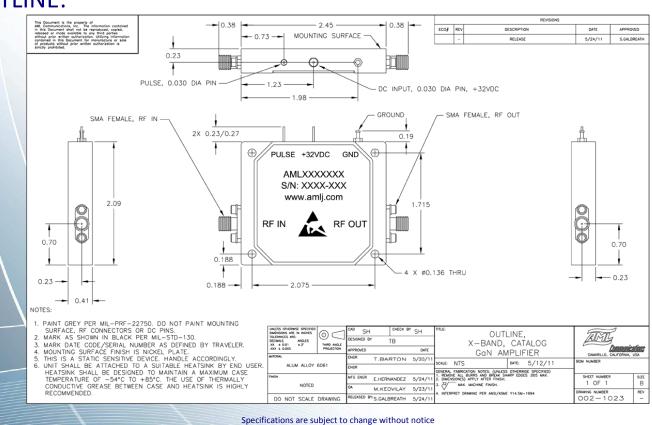
FEATURES:

- AML811P5011 is a 7.8-11.0GHz 25-Watt GaN power amplifier
- Amplifier is in hermetically sealed housing with field removable SMA (f) connectors
- ATP (100%) testing includes Gain, Flatness, NF, Psat, VSWR, and DC Current measurement at room temperature.
- Dimensions: 2.45"L x 2.09"W x 0.41"H

ELECTRICAL SPECIFICATIONS:

PARAMETER	MIN	ТҮР	MAX	UNITS
Frequency Range	7.8		11.0	GHz
Gain	45			dB
Gain Flatness vs Freq.			±3.0	dB
Noise Figure			6.0	dB
Psat	43	44		dBm
Psat		25		Watts
DC Voltage		28		V
DC Current		2.8		А
PAE		30		%
TTL Control	DC On/Off			
Switching Speed	On: 250 ns nom			
50% TTL – 90% RF/10% RF	Off: 500 ns nom			
DC Power in Off condition	<10% full RF			

Specifications above are at +25°C unless stated otherwise



OUTLINE:

Microsemi-RFIS (Formerly AML) | Camarillo, CA | 805-388-1345 | <u>sales.support@microsemi.com</u> | www.microsemi.com